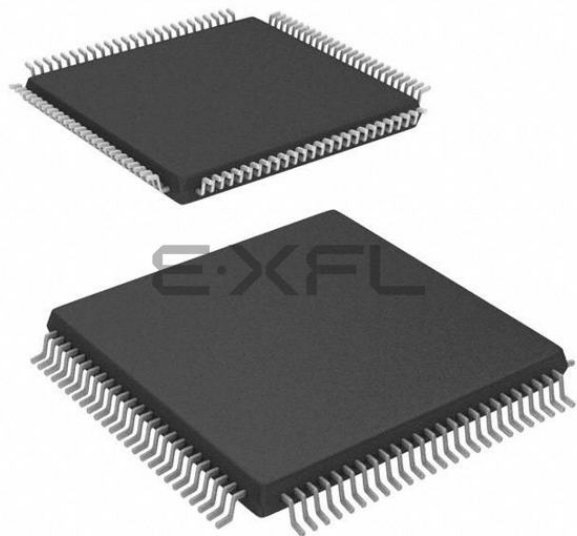




Welcome to [E-XFL.COM](https://www.e-xfl.com)

Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	216
Number of Logic Elements/Cells	972
Total RAM Bits	24576
Number of I/O	60
Number of Gates	30000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc2s30-6vqg100c

Signals

There are two kinds of pins that are used to configure Spartan-II devices: Dedicated pins perform only specific configuration-related functions; the other pins can serve as general purpose I/Os once user operation has begun.

The dedicated pins comprise the mode pins (M2, M1, M0), the configuration clock pin (CCLK), the $\overline{\text{PROGRAM}}$ pin, the DONE pin and the boundary-scan pins (TDI, TDO, TMS, TCK). Depending on the selected configuration mode, CCLK may be an output generated by the FPGA, or may be generated externally, and provided to the FPGA as an input.

Note that some configuration pins can act as outputs. For correct operation, these pins require a V_{CCO} of 3.3V to drive an LVTTTL signal or 2.5V to drive an LVC MOS signal. All the relevant pins fall in banks 2 or 3. The $\overline{\text{CS}}$ and $\overline{\text{WRITE}}$ pins for Slave Parallel mode are located in bank 1.

For a more detailed description than that given below, see "Pinout Tables" in Module 4 and [XAPP176](#), *Spartan-II FPGA Series Configuration and Readback*.

The Process

The sequence of steps necessary to configure Spartan-II devices are shown in [Figure 11](#). The overall flow can be divided into three different phases.

- Initiating Configuration
- Configuration memory clear
- Loading data frames
- Start-up

The memory clearing and start-up phases are the same for all configuration modes; however, the steps for the loading of data frames are different. Thus, the details for data frame loading are described separately in the sections devoted to each mode.

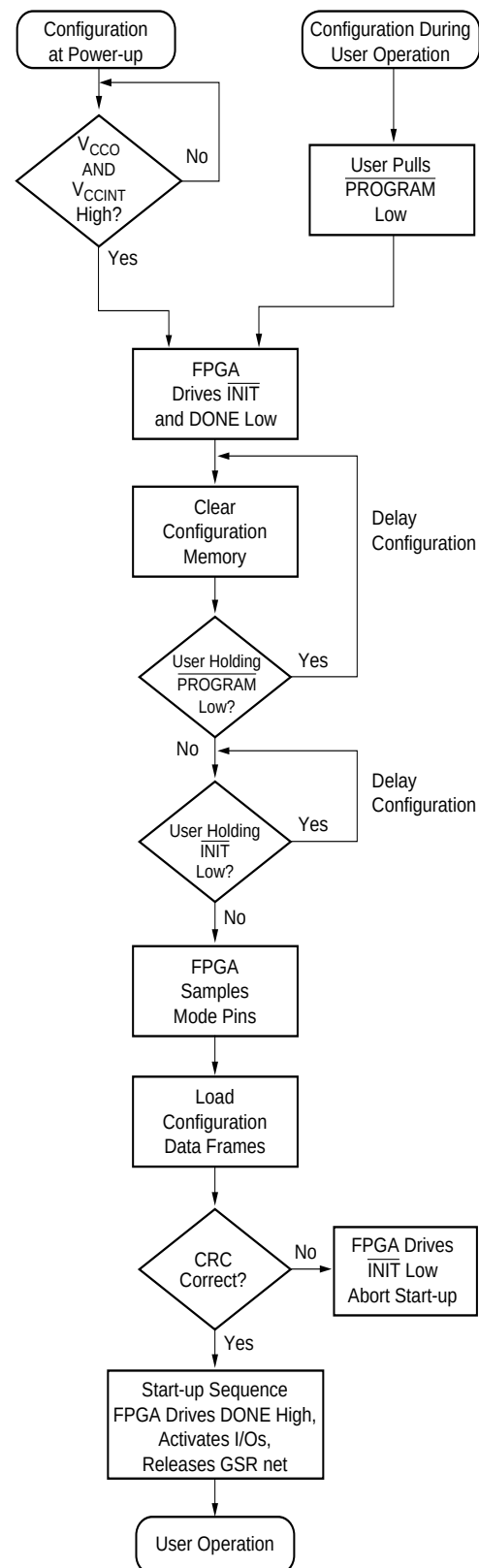
Initiating Configuration

There are two different ways to initiate the configuration process: applying power to the device or asserting the $\overline{\text{PROGRAM}}$ input.

Configuration on power-up occurs automatically unless it is delayed by the user, as described in a separate section below. The waveform for configuration on power-up is shown in [Figure 12](#), page 19. Before configuration can begin, V_{CCO} Bank 2 must be greater than 1.0V. Furthermore, all V_{CCINT} power pins must be connected to a 2.5V supply. For more information on delaying configuration, see "Clearing Configuration Memory," page 19.

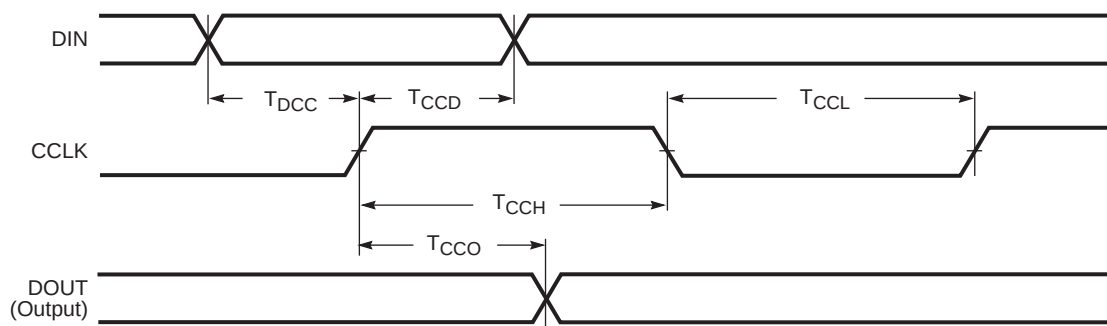
Once in user operation, the device can be re-configured simply by pulling the $\overline{\text{PROGRAM}}$ pin Low. The device acknowledges the beginning of the configuration process

by driving DONE Low, then enters the memory-clearing phase.



DS001_11_111501

Figure 11: Configuration Flow Diagram



DS001_16_032300

Symbol		Description		Units
T_{DCC}	CCLK	DIN setup	5	ns, min
T_{CCD}		DIN hold	0	ns, min
T_{CCO}		DOUT	12	ns, max
T_{CCH}		High time	5	ns, min
T_{CCL}		Low time	5	ns, min
F_{CC}		Maximum frequency	66	MHz, max

Figure 16: Slave Serial Mode Timing

BUFGDLL Pin Descriptions

Use the BUFGDLL macro as the simplest way to provide zero propagation delay for a high-fanout on-chip clock from an external input. This macro uses the IBUFG, CLKDLL and BUFG primitives to implement the most basic DLL application as shown in Figure 25.

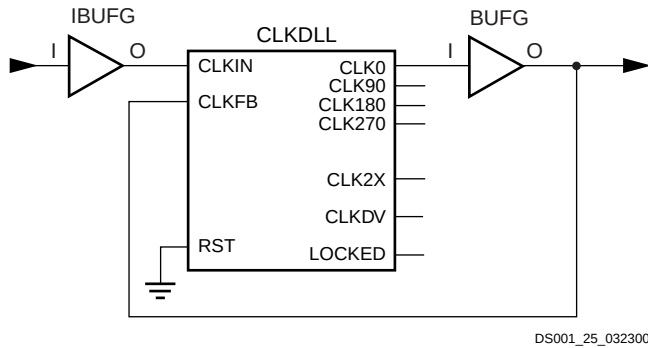


Figure 25: BUFGDLL Block Diagram

This macro does not provide access to the advanced clock domain controls or to the clock multiplication or clock division features of the DLL. This macro also does not provide access to the RST or LOCKED pins of the DLL. For access to these features, a designer must use the DLL primitives described in the following sections.

Source Clock Input — I

The I pin provides the user source clock, the clock signal on which the DLL operates, to the BUFGDLL. For the BUFGDLL macro the source clock frequency must fall in the low frequency range as specified in the data sheet. The BUFGDLL requires an external signal source clock. Therefore, only an external input port can source the signal that drives the BUFGDLL I pin.

Clock Output — O

The clock output pin O represents a delay-compensated version of the source clock (I) signal. This signal, sourced by a global clock buffer BUFG primitive, takes advantage of the dedicated global clock routing resources of the device.

The output clock has a 50/50 duty cycle unless you deactivate the duty cycle correction property.

CLKDLL Primitive Pin Descriptions

The library CLKDLL primitives provide access to the complete set of DLL features needed when implementing more complex applications with the DLL.

Source Clock Input — CLKIN

The CLKIN pin provides the user source clock (the clock signal on which the DLL operates) to the DLL. The CLKIN frequency must fall in the ranges specified in the data sheet. A global clock buffer (BUFG) driven from another CLKDLL

or one of the global clock input buffers (IBUFG) on the same edge of the device (top or bottom) must source this clock signal.

Feedback Clock Input — CLKFB

The DLL requires a reference or feedback signal to provide the delay-compensated output. Connect only the CLK0 or CLK2X DLL outputs to the feedback clock input (CLKFB) pin to provide the necessary feedback to the DLL. Either a global clock buffer (BUFG) or one of the global clock input buffers (IBUFG) on the same edge of the device (top or bottom) must source this clock signal.

If an IBUFG sources the CLKFB pin, the following special rules apply.

1. An external input port must source the signal that drives the IBUFG I pin.
2. The CLK2X output must feed back to the device if both the CLK0 and CLK2X outputs are driving off chip devices.
3. That signal must directly drive only OBUFs and nothing else.

These rules enable the software to determine which DLL clock output sources the CLKFB pin.

Reset Input — RST

When the reset pin RST activates, the LOCKED signal deactivates within four source clock cycles. The RST pin, active High, must either connect to a dynamic signal or be tied to ground. As the DLL delay taps reset to zero, glitches can occur on the DLL clock output pins. Activation of the RST pin can also severely affect the duty cycle of the clock output pins. Furthermore, the DLL output clocks no longer deskew with respect to one another. The DLL must be reset when the input clock frequency changes, if the device is reconfigured in Boundary-Scan mode, if the device undergoes a hot swap, and after the device is configured if the input clock is not stable during the startup sequence.

2x Clock Output — CLK2X

The output pin CLK2X provides a frequency-doubled clock with an automatic 50/50 duty-cycle correction. Until the CLKDLL has achieved lock, the CLK2X output appears as a 1x version of the input clock with a 25/75 duty cycle. This behavior allows the DLL to lock on the correct edge with respect to source clock. This pin is not available on the CLKDLLHF primitive.

Clock Divide Output — CLKDV

The clock divide output pin CLKDV provides a lower frequency version of the source clock. The CLKDV_DIVIDE property controls CLKDV such that the source clock is divided by N where N is either 1.5, 2, 2.5, 3, 4, 5, 8, or 16.

This feature provides automatic duty cycle correction. The CLKDV output pin has a 50/50 duty cycle for all values of the

At the third rising edge of CLKA, the T_{BCCS} parameter is violated with two writes to memory location 0x0F. The DOA and DOB busses reflect the contents of the DIA and DIB busses, but the stored value at 0x7E is invalid.

At the fourth rising edge of CLKA, a read operation is performed at memory location 0x0F and invalid data is present on the DOA bus. Port B also executes a read operation to memory location 0x0F and also reads invalid data.

At the fifth rising edge of CLKA a read operation is performed that does not violate the T_{BCCS} parameter to the previous write of 0x7E by Port B. The DOA bus reflects the recently written value by Port B.

Initialization

The block RAM memory can initialize during the device configuration sequence. The 16 initialization properties of 64 hex values each (a total of 4096 bits) set the initialization of each RAM. These properties appear in [Table 14](#). Any initialization properties not explicitly set configure as zeros. Partial initialization strings pad with zeros. Initialization strings greater than 64 hex values generate an error. The RAMs can be simulated with the initialization values using generics in VHDL simulators and parameters in Verilog simulators.

Initialization in VHDL

The block RAM structures may be initialized in VHDL for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the VHDL code uses a generic to pass the initialization.

Initialization in Verilog

The block RAM structures may be initialized in Verilog for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the Verilog code uses a defparam to pass the initialization.

Block Memory Generation

The CORE Generator™ software generates memory structures using the block RAM features. This program outputs VHDL or Verilog simulation code templates and an EDIF file for inclusion in a design.

Table 14: RAM Initialization Properties

Property	Memory Cells
INIT_00	255 to 0
INIT_01	511 to 256
INIT_02	767 to 512
INIT_03	1023 to 768
INIT_04	1279 to 1024

Table 14: RAM Initialization Properties

Property	Memory Cells
INIT_05	1535 to 1280
INIT_06	1791 to 1536
INIT_07	2047 to 1792
INIT_08	2303 to 2048
INIT_09	2559 to 2304
INIT_0a	2815 to 2560
INIT_0b	3071 to 2816
INIT_0c	3327 to 3072
INIT_0d	3583 to 3328
INIT_0e	3839 to 3584
INIT_0f	4095 to 3840

For design examples and more information on using the Block RAM, see [XAPP173, Using Block SelectRAM+ Memory in Spartan-II FPGAs](#).

Using Versatile I/O

The Spartan-II FPGA family includes a highly configurable, high-performance I/O resource called Versatile I/O to provide support for a wide variety of I/O standards. The Versatile I/O resource is a robust set of features including programmable control of output drive strength, slew rate, and input delay and hold time. Taking advantage of the flexibility and Versatile I/O features and the design considerations described in this document can improve and simplify system level design.

Introduction

As FPGAs continue to grow in size and capacity, the larger and more complex systems designed for them demand an increased variety of I/O standards. Furthermore, as system clock speeds continue to increase, the need for high-performance I/O becomes more important. While chip-to-chip delays have an increasingly substantial impact on overall system speed, the task of achieving the desired system performance becomes more difficult with the proliferation of low-voltage I/O standards. Versatile I/O, the revolutionary input/output resources of Spartan-II devices, has resolved this potential problem by providing a highly configurable, high-performance alternative to the I/O resources of more conventional programmable devices. The Spartan-II FPGA Versatile I/O features combine the flexibility and time-to-market advantages of programmable logic with the high performance previously available only with ASICs and custom ICs.

Each Versatile I/O block can support up to 16 I/O standards. Supporting such a variety of I/O standards allows the

LVTTL output buffers have selectable drive strengths.

The format for LVTTL OBUF primitive names is as follows.

OBUF_<slew_rate>_<drive_strength>

<slew_rate> is either F (Fast), or S (Slow) and <drive_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24). The default is slew rate limited with 12 mA drive.

OBUF placement restrictions require that within a given V_{CCO} bank each OBUF share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within any V_{CCO} bank.

Table 17 summarizes the output compatibility requirements. The LOC property can specify a location for the OBUF.

Table 17: Output Standards Compatibility Requirements

Rule 1	Only outputs with standards which share compatible V_{CCO} may be used within the same bank.
Rule 2	There are no placement restrictions for outputs with standards that do not require a V_{CCO} .
V_{CCO}	Compatible Standards
3.3	LVTTL, SSTL3_I, SSTL3_II, CTT, AGP, GTL, GTL+, PCI33_3, PCI66_3
2.5	SSTL2_I, SSTL2_II, LVCMOS2, GTL, GTL+
1.5	HSTL_I, HSTL_III, HSTL_IV, GTL, GTL+

OBUFT

The generic 3-state output buffer OBUFT, shown in Figure 39, typically implements 3-state outputs or bidirectional I/O.

With no extension or property specified for the generic OBUFT primitive, the assumed standard is slew rate limited LVTTL with 12 mA drive strength.

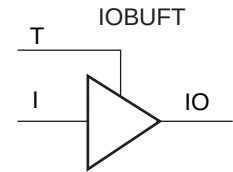
The LVTTL OBUFT can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL 3-state output buffers have selectable drive strengths.

The format for LVTTL OBUFT primitive names is as follows.

OBUFT_<slew_rate>_<drive_strength>

<slew_rate> can be either F (Fast), or S (Slow) and <drive_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).



DS001_39_032300

Figure 39: 3-State Output Buffer Primitive (OBUFT)

The Versatile I/O OBUFT placement restrictions require that within a given V_{CCO} bank each OBUFT share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within the same V_{CCO} bank.

The LOC property can specify a location for the OBUFT.

3-state output buffers and bidirectional buffers can have either a weak pull-up resistor, a weak pull-down resistor, or a weak "keeper" circuit. Control this feature by adding the appropriate primitive to the output net of the OBUFT (PULLUP, PULLDOWN, or KEEPER).

The weak "keeper" circuit requires the input buffer within the IOB to sample the I/O signal. So, OBUFTs programmed for an I/O standard that requires a V_{REF} have automatic placement of a V_{REF} in the bank with an OBUFT configured with a weak "keeper" circuit. This restriction does not affect most circuit design as applications using an OBUFT configured with a weak "keeper" typically implement a bidirectional I/O. In this case the IBUF (and the corresponding V_{REF}) are explicitly placed.

The LOC property can specify a location for the OBUFT.

IOBUF

Use the IOBUF primitive for bidirectional signals that require both an input buffer and a 3-state output buffer with an active high 3-state pin. The generic input/output buffer IOBUF appears in Figure 40.

With no extension or property specified for the generic IOBUF primitive, the assumed standard is LVTTL input buffer and slew rate limited LVTTL with 12 mA drive strength for the output buffer.

The LVTTL IOBUF can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL bidirectional buffers have selectable output drive strengths.

The format for LVTTL IOBUF primitive names is as follows:

SSTL3 Class I

A sample circuit illustrating a valid termination technique for SSTL3_I appears in Figure 47. DC voltage specifications appear in Table 25 for the SSTL3_I standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.

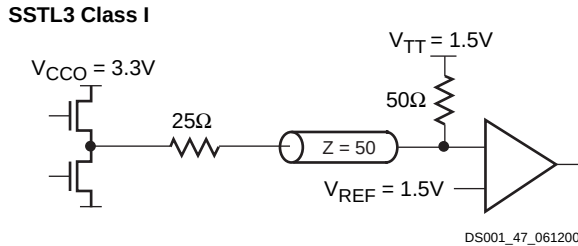


Figure 47: Terminated SSTL3 Class I

Table 25: SSTL3_I Voltage Specifications

Parameter	Min	Typ	Max
V_{CCO}	3.0	3.3	3.6
$V_{REF} = 0.45 \times V_{CCO}$	1.3	1.5	1.7
$V_{TT} = V_{REF}$	1.3	1.5	1.7
$V_{IH} \geq V_{REF} + 0.2$	1.5	1.7	3.9 ⁽¹⁾
$V_{IL} \leq V_{REF} - 0.2$	-0.3 ⁽²⁾	1.3	1.5
$V_{OH} \geq V_{REF} + 0.6$	1.9	-	-
$V_{OL} \leq V_{REF} - 0.6$	-	-	1.1
I_{OH} at V_{OH} (mA)	-8	-	-
I_{OL} at V_{OL} (mA)	8	-	-

Notes:

- V_{IH} maximum is $V_{CCO} + 0.3$.
- V_{IL} minimum does not conform to the formula.

SSTL3 Class II

A sample circuit illustrating a valid termination technique for SSTL3_II appears in Figure 48. DC voltage specifications appear in Table 26 for the SSTL3_II standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.

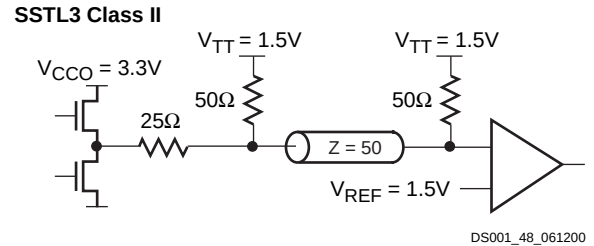


Figure 48: Terminated SSTL3 Class II

Table 26: SSTL3_II Voltage Specifications

Parameter	Min	Typ	Max
V_{CCO}	3.0	3.3	3.6
$V_{REF} = 0.45 \times V_{CCO}$	1.3	1.5	1.7
$V_{TT} = V_{REF}$	1.3	1.5	1.7
$V_{IH} \geq V_{REF} + 0.2$	1.5	1.7	3.9 ⁽¹⁾
$V_{IL} \leq V_{REF} - 0.2$	-0.3 ⁽²⁾	1.3	1.5
$V_{OH} \geq V_{REF} + 0.8$	2.1	-	-
$V_{OL} \leq V_{REF} - 0.8$	-	-	0.9
I_{OH} at V_{OH} (mA)	-16	-	-
I_{OL} at V_{OL} (mA)	16	-	-

Notes:

- V_{IH} maximum is $V_{CCO} + 0.3$.
- V_{IL} minimum does not conform to the formula.

SSTL2_I

A sample circuit illustrating a valid termination technique for SSTL2_I appears in Figure 49. DC voltage specifications appear in Table 27 for the SSTL2_I standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics

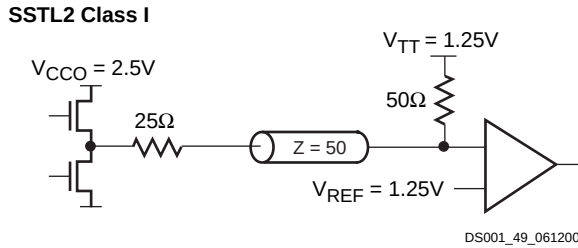


Figure 49: Terminated SSTL2 Class I

Table 27: SSTL2_I Voltage Specifications

Parameter	Min	Typ	Max
V_{CCO}	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \geq V_{REF} + 0.18$	1.33	1.43	3.0 ⁽²⁾
$V_{IL} \leq V_{REF} - 0.18$	-0.3 ⁽³⁾	1.07	1.17
$V_{OH} \geq V_{REF} + 0.61$	1.76	-	-
$V_{OL} \leq V_{REF} - 0.61$	-	-	0.74
I_{OH} at V_{OH} (mA)	-7.6	-	-
I_{OL} at V_{OL} (mA)	7.6	-	-

Notes:

1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
2. V_{IH} maximum is $V_{CCO} + 0.3$.
3. V_{IL} minimum does not conform to the formula.

SSTL2 Class II

A sample circuit illustrating a valid termination technique for SSTL2_II appears in Figure 50. DC voltage specifications appear in Table 28 for the SSTL2_II standard. See "DC Specifications" in Module 3 for the actual FPGA characteristics.

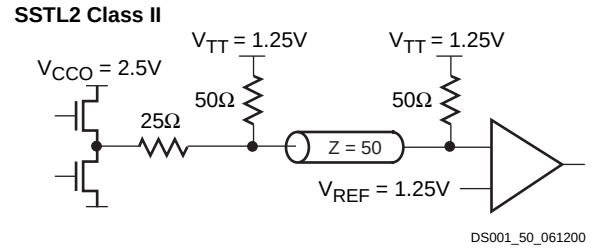


Figure 50: Terminated SSTL2 Class II

Table 28: SSTL2_II Voltage Specifications

Parameter	Min	Typ	Max
V_{CCO}	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} \geq V_{REF} + 0.18$	1.33	1.43	3.0 ⁽²⁾
$V_{IL} \leq V_{REF} - 0.18$	-0.3 ⁽³⁾	1.07	1.17
$V_{OH} \geq V_{REF} + 0.8$	1.95	-	-
$V_{OL} \leq V_{REF} - 0.8$	-	-	0.55
I_{OH} at V_{OH} (mA)	-15.2	-	-
I_{OL} at V_{OL} (mA)	15.2	-	-

Notes:

1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
2. V_{IH} maximum is $V_{CCO} + 0.3$.
3. V_{IL} minimum does not conform to the formula.

Power-On Requirements

Spartan-II FPGAs require that a minimum supply current I_{CCPO} be provided to the V_{CCINT} lines for a successful power-on. If more current is available, the FPGA can consume more than I_{CCPO} minimum, though this cannot adversely affect reliability.

A maximum limit for I_{CCPO} is not specified. Therefore the use of foldback/crowbar supplies and fuses deserves special attention. In these cases, limit the I_{CCPO} current to a level below the trip point for over-current protection in order to avoid inadvertently shutting down the supply.

Symbol	Description	Conditions		New Requirements ⁽¹⁾ For Devices with Date Code 0321 or Later		Old Requirements ⁽¹⁾ For Devices with Date Code before 0321		Units
		Junction Temperature ⁽²⁾	Device Temperature Grade	Min	Max	Min	Max	
I_{CCPO} ⁽³⁾	Total V_{CCINT} supply current required during power-on	$-40^{\circ}\text{C} \leq T_J < -20^{\circ}\text{C}$	Industrial	1.50	-	2.00	-	A
		$-20^{\circ}\text{C} \leq T_J < 0^{\circ}\text{C}$	Industrial	1.00	-	2.00	-	A
		$0^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$	Commercial	0.25	-	0.50	-	A
		$85^{\circ}\text{C} < T_J \leq 100^{\circ}\text{C}$	Industrial	0.50	-	0.50	-	A
T_{CCPO} ^(4,5)	V_{CCINT} ramp time	$-40^{\circ}\text{C} \leq T_J \leq 100^{\circ}\text{C}$	All	-	50	-	50	ms

Notes:

- The date code is printed on the top of the device's package. See the "Device Part Marking" section in Module 1.
- The expected T_J range for the design determines the I_{CCPO} minimum requirement. Use the applicable ranges in the junction temperature column to find the associated current values in the appropriate new or old requirements column according to the date code. Then choose the highest of these current values to serve as the minimum I_{CCPO} requirement that must be met. For example, if the junction temperature for a given design is $-25^{\circ}\text{C} \leq T_J \leq 75^{\circ}\text{C}$, then the new minimum I_{CCPO} requirement is 1.5A. If $5^{\circ}\text{C} \leq T_J \leq 90^{\circ}\text{C}$, then the new minimum I_{CCPO} requirement is 0.5A.
- The I_{CCPO} requirement applies for a brief time (commonly only a few milliseconds) when V_{CCINT} ramps from 0 to 2.5V.
- The ramp time is measured from GND to V_{CCINT} max on a fully loaded board.
- During power-on, the V_{CCINT} ramp must increase steadily in voltage with no dips.
- For more information on designing to meet the power-on specifications, refer to the application note [XAPP450 "Power-On Current Requirements for the Spartan-II and Spartan-II-E Families"](#)

DC Input and Output Levels

Values for V_{IL} and V_{IH} are recommended input voltages. Values for V_{OL} and V_{OH} are guaranteed output voltages over the recommended operating conditions. Only selected standards are tested. These are chosen to ensure that all

standards meet their specifications. The selected standards are tested at minimum V_{CCO} with the respective I_{OL} and I_{OH} currents shown. Other standards are sample tested.

Input/Output Standard	V_{IL}		V_{IH}		V_{OL}	V_{OH}	I_{OL}	I_{OH}
	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
LVTTL ⁽¹⁾	-0.5	0.8	2.0	5.5	0.4	2.4	24	-24
LVC MOS2	-0.5	0.7	1.7	5.5	0.4	1.9	12	-12
PCI, 3.3V	-0.5	44% V_{CCINT}	60% V_{CCINT}	$V_{CCO} + 0.5$	10% V_{CCO}	90% V_{CCO}	Note (2)	Note (2)
PCI, 5.0V	-0.5	0.8	2.0	5.5	0.55	2.4	Note (2)	Note (2)
GTL	-0.5	$V_{REF} - 0.05$	$V_{REF} + 0.05$	3.6	0.4	N/A	40	N/A
GTL+	-0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	3.6	0.6	N/A	36	N/A
HSTL I	-0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	3.6	0.4	$V_{CCO} - 0.4$	8	-8
HSTL III	-0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	3.6	0.4	$V_{CCO} - 0.4$	24	-8
HSTL IV	-0.5	$V_{REF} - 0.1$	$V_{REF} + 0.1$	3.6	0.4	$V_{CCO} - 0.4$	48	-8
SSTL3 I	-0.5	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	$V_{REF} - 0.6$	$V_{REF} + 0.6$	8	-8
SSTL3 II	-0.5	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	$V_{REF} - 0.8$	$V_{REF} + 0.8$	16	-16
SSTL2 I	-0.5	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	$V_{REF} - 0.6$	$V_{REF} + 0.6$	7.6	-7.6
SSTL2 II	-0.5	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	$V_{REF} - 0.8$	$V_{REF} + 0.8$	15.2	-15.2

IOB Output Switching Characteristics

Output delays terminating at a pad are specified for LVTTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays with the values shown in "IOB Output Delay Adjustments for Different Standards," page 59.

Symbol	Description	Speed Grade				Units
		-6		-5		
		Min	Max	Min	Max	
Propagation Delays						
T _{IOOP}	O input to pad	-	2.9	-	3.4	ns
T _{IOOLP}	O input to pad via transparent latch	-	3.4	-	4.0	ns
3-state Delays						
T _{IOTHZ}	T input to pad high-impedance ⁽¹⁾	-	2.0	-	2.3	ns
T _{IOTON}	T input to valid data on pad	-	3.0	-	3.6	ns
T _{IOTLPHZ}	T input to pad high impedance via transparent latch ⁽¹⁾	-	2.5	-	2.9	ns
T _{IOTLPON}	T input to valid data on pad via transparent latch	-	3.5	-	4.2	ns
T _{GTS}	GTS to pad high impedance ⁽¹⁾	-	5.0	-	5.9	ns
Sequential Delays						
T _{IOCKP}	Clock CLK to pad	-	2.9	-	3.4	ns
T _{IOCKHZ}	Clock CLK to pad high impedance (synchronous) ⁽¹⁾	-	2.3	-	2.7	ns
T _{IOCKON}	Clock CLK to valid data on pad (synchronous)	-	3.3	-	4.0	ns
Setup/Hold Times with Respect to Clock CLK ⁽²⁾						
T _{IOOCK} / T _{IOCKO}	O input	1.1 / 0	-	1.3 / 0	-	ns
T _{IOOCECK} / T _{IOCKOCE}	OCE input	0.9 / 0.01	-	0.9 / 0.01	-	ns
T _{IOSRCKO} / T _{IOCKOSR}	SR input (OFF)	1.2 / 0	-	1.3 / 0	-	ns
T _{IOTCK} / T _{IOCKT}	3-state setup times, T input	0.8 / 0	-	0.9 / 0	-	ns
T _{IOTCECK} / T _{IOCKTCE}	3-state setup times, TCE input	1.0 / 0	-	1.0 / 0	-	ns
T _{IOSRCKT} / T _{IOCKTSR}	3-state setup times, SR input (TFF)	1.1 / 0	-	1.2 / 0	-	ns
Set/Reset Delays						
T _{IOSRP}	SR input to pad (asynchronous)	-	3.7	-	4.4	ns
T _{IOSRHZ}	SR input to pad high impedance (asynchronous) ⁽¹⁾	-	3.1	-	3.7	ns
T _{IOSRON}	SR input to valid data on pad (asynchronous)	-	4.1	-	4.9	ns
T _{IOGSRQ}	GSR to pad	-	9.9	-	11.7	ns

Notes:

- Three-state turn-off delays should not be adjusted.
- A zero hold time listing indicates no hold time or a negative hold time.

DLL Timing Parameters

All devices are 100 percent functionally tested. Because of the difficulty in directly measuring many internal timing parameters, those parameters are derived from benchmark

timing patterns. The following guidelines reflect worst-case values across the recommended operating conditions.

Symbol	Description	Speed Grade				Units
		-6		-5		
		Min	Max	Min	Max	
F _{CLKINHF}	Input clock frequency (CLKDLLHF)	60	200	60	180	MHz
F _{CLKINLF}	Input clock frequency (CLKDLL)	25	100	25	90	MHz
T _{DLLPWHF}	Input clock pulse width (CLKDLLHF)	2.0	-	2.4	-	ns
T _{DLLPWLF}	Input clock pulse width (CLKDLL)	2.5	-	3.0	-	ns

DLL Clock Tolerance, Jitter, and Phase Information

All DLL output jitter and phase specifications were determined through statistical measurement at the package pins using a clock mirror configuration and matched drivers.

Figure 52, page 63, provides definitions for various parameters in the table below.

Symbol	Description	F _{CLKIN}	CLKDLLHF		CLKDLL		Units
			Min	Max	Min	Max	
T _{IPTOL}	Input clock period tolerance		-	1.0	-	1.0	ns
T _{IJITCC}	Input clock jitter tolerance (cycle-to-cycle)		-	±150	-	±300	ps
T _{LOCK}	Time required for DLL to acquire lock	> 60 MHz	-	20	-	20	μs
		50-60 MHz	-	-	-	25	μs
		40-50 MHz	-	-	-	50	μs
		30-40 MHz	-	-	-	90	μs
		25-30 MHz	-	-	-	120	μs
T _{OJITCC}	Output jitter (cycle-to-cycle) for any DLL clock output ⁽¹⁾		-	±60	-	±60	ps
T _{PHIO}	Phase offset between CLKIN and CLKO ⁽²⁾		-	±100	-	±100	ps
T _{PHOO}	Phase offset between clock outputs on the DLL ⁽³⁾		-	±140	-	±140	ps
T _{PHIOM}	Maximum phase difference between CLKIN and CLKO ⁽⁴⁾		-	±160	-	±160	ps
T _{PHOOM}	Maximum phase difference between clock outputs on the DLL ⁽⁵⁾		-	±200	-	±200	ps

Notes:

- Output Jitter** is cycle-to-cycle jitter measured on the DLL output clock, *excluding* input clock jitter.
- Phase Offset between CLKIN and CLKO** is the worst-case fixed time difference between rising edges of CLKIN and CLKO, *excluding* output jitter and input clock jitter.
- Phase Offset between Clock Outputs on the DLL** is the worst-case fixed time difference between rising edges of any two DLL outputs, *excluding* Output Jitter and input clock jitter.
- Maximum Phase Difference between CLKIN and CLKO** is the sum of Output Jitter and Phase Offset between CLKIN and CLKO, or the greatest difference between CLKIN and CLKO rising edges due to DLL alone (*excluding* input clock jitter).
- Maximum Phase Difference between Clock Outputs on the DLL** is the sum of Output Jitter and Phase Offset between any two DLL clock outputs, or the greatest difference between any two DLL output rising edges due to DLL alone (*excluding* input clock jitter).

CLB Switching Characteristics

Delays originating at F/G inputs vary slightly according to the input used. The values listed below are worst-case. Precise values are provided by the timing analyzer.

Symbol	Description	Speed Grade				Units
		-6		-5		
		Min	Max	Min	Max	
Combinatorial Delays						
T _{ILO}	4-input function: F/G inputs to X/Y outputs	-	0.6	-	0.7	ns
T _{IF5}	5-input function: F/G inputs to F5 output	-	0.7	-	0.9	ns
T _{IF5X}	5-input function: F/G inputs to X output	-	0.9	-	1.1	ns
T _{IF6Y}	6-input function: F/G inputs to Y output via F6 MUX	-	1.0	-	1.1	ns
T _{F5INY}	6-input function: F5IN input to Y output	-	0.4	-	0.4	ns
T _{IFNCTL}	Incremental delay routing through transparent latch to XQ/YQ outputs	-	0.7	-	0.9	ns
T _{BYYB}	BY input to YB output	-	0.6	-	0.7	ns
Sequential Delays						
T _{CKO}	FF clock CLK to XQ/YQ outputs	-	1.1	-	1.3	ns
T _{CKLO}	Latch clock CLK to XQ/YQ outputs	-	1.2	-	1.5	ns
Setup/Hold Times with Respect to Clock CLK ⁽¹⁾						
T _{ICK} / T _{CKI}	4-input function: F/G inputs	1.3 / 0	-	1.4 / 0	-	ns
T _{IF5CK} / T _{CKIF5}	5-input function: F/G inputs	1.6 / 0	-	1.8 / 0	-	ns
T _{F5INCK} / T _{CKF5IN}	6-input function: F5IN input	1.0 / 0	-	1.1 / 0	-	ns
T _{IF6CK} / T _{CKIF6}	6-input function: F/G inputs via F6 MUX	1.6 / 0	-	1.8 / 0	-	ns
T _{DICK} / T _{CKDI}	BX/BY inputs	0.8 / 0	-	0.8 / 0	-	ns
T _{CECK} / T _{CKCE}	CE input	0.9 / 0	-	0.9 / 0	-	ns
T _{RCK} / T _{CKR}	SR/BY inputs (synchronous)	0.8 / 0	-	0.8 / 0	-	ns
Clock CLK						
T _{CH}	Minimum pulse width, High	-	1.9	-	1.9	ns
T _{CL}	Minimum pulse width, Low	-	1.9	-	1.9	ns
Set/Reset						
T _{RPW}	Minimum pulse width, SR/BY inputs	3.1	-	3.1	-	ns
T _{RQ}	Delay from SR/BY inputs to XQ/YQ outputs (asynchronous)	-	1.1	-	1.3	ns
T _{IOGSRQ}	Delay from GSR to XQ/YQ outputs	-	9.9	-	11.7	ns
F _{TOG}	Toggle frequency (for export control)	-	263	-	263	MHz

Notes:

1. A zero hold time listing indicates no hold time or a negative hold time.

Revision History

Date	Version No.	Description
09/18/00	2.0	Sectioned the Spartan-II Family data sheet into four modules. Updated timing to reflect the latest speed files. Added current supply numbers and XC2S200 -5 timing numbers. Approved -5 timing numbers as preliminary information with exceptions as noted.
11/02/00	2.1	Removed Power Down feature.
01/19/01	2.2	DC and timing numbers updated to Preliminary for the XC2S50 and XC2S100. Industrial power-on current specifications and -6 DLL timing numbers added. Power-on specification clarified.
03/09/01	2.3	Added note on power sequencing. Clarified power-on current requirement.
08/28/01	2.4	Added -6 preliminary timing. Added typical and industrial standby current numbers. Specified min. power-on current by junction temperature instead of by device type (Commercial vs. Industrial). Eliminated minimum V_{CCINT} ramp time requirement. Removed footnote limiting DLL operation to the Commercial temperature range.
07/26/02	2.5	Clarified that I/O leakage current is specified over the Recommended Operating Conditions for V_{CCINT} and V_{CCO} .
08/26/02	2.6	Added references for XAPP450 to Power-On Current Specification.
09/03/03	2.7	Added relaxed minimum power-on current (I_{CCPO}) requirements to page 53 . On page 64 , moved T_{RPW} values from maximum to minimum column.
06/13/08	2.8	Updated I/O measurement thresholds. Updated description and links. Updated all modules for continuous page, figure, and table numbering. Synchronized all modules to v2.8.

XC2S15 Device Pinouts (Continued)

XC2S15 Pad Name		VQ100	TQ144	CS144	Bndry Scan
Function	Bank				
GND	-	-	P61	J12	-
I/O (D5)	3	P57	P60	J13	245
I/O	3	P58	P59	H10	248
I/O, V _{REF}	3	P59	P58	H11	251
I/O (D4)	3	P60	P57	H12	254
I/O	3	-	P56	H13	257
V _{CCINT}	-	P61	P55	G12	-
I/O, TRDY ⁽¹⁾	3	P62	P54	G13	260
V _{CCO}	3	P63	P53	G11	-
V _{CCO}	2	P63	P53	G11	-
GND	-	P64	P52	G10	-
I/O, IRDY ⁽¹⁾	2	P65	P51	F13	263
I/O	2	-	P50	F12	266
I/O (D3)	2	P66	P49	F11	269
I/O, V _{REF}	2	P67	P48	F10	272
I/O	2	P68	P47	E13	275
I/O (D2)	2	P69	P46	E12	278
GND	-	-	P45	E11	-
I/O (D1)	2	P70	P44	E10	281
I/O	2	P71	P43	D13	284
I/O, V _{REF}	2	P72	P41	D11	287
I/O	2	-	P40	C13	290
I/O (DIN, D0)	2	P73	P39	C12	293
I/O (DOUT, BUSY)	2	P74	P38	C11	296
CCLK	2	P75	P37	B13	299
V _{CCO}	2	P76	P36	B12	-
V _{CCO}	1	P76	P35	A13	-
TDO	2	P77	P34	A12	-
GND	-	P78	P33	B11	-
TDI	-	P79	P32	A11	-
I/O ($\overline{\text{CS}}$)	1	P80	P31	D10	0
I/O ($\overline{\text{WRITE}}$)	1	P81	P30	C10	3
I/O	1	-	P29	B10	6
I/O, V _{REF}	1	P82	P28	A10	9
I/O	1	P83	P27	D9	12
I/O	1	P84	P26	C9	15
GND	-	-	P25	B9	-
V _{CCINT}	-	P85	P24	A9	-
I/O	1	-	P23	D8	18
I/O	1	-	P22	C8	21

XC2S15 Device Pinouts (Continued)

XC2S15 Pad Name		VQ100	TQ144	CS144	Bndry Scan
Function	Bank				
I/O, V _{REF}	1	P86	P21	B8	24
I/O	1	-	P20	A8	27
I/O	1	P87	P19	B7	30
I, GCK2	1	P88	P18	A7	36
GND	-	P89	P17	C7	-
V _{CCO}	1	P90	P16	D7	-
V _{CCO}	0	P90	P16	D7	-
I, GCK3	0	P91	P15	A6	37
V _{CCINT}	-	P92	P14	B6	-
I/O	0	-	P13	C6	44
I/O, V _{REF}	0	P93	P12	D6	47
I/O	0	-	P11	A5	50
I/O	0	-	P10	B5	53
V _{CCINT}	-	P94	P9	C5	-
GND	-	-	P8	D5	-
I/O	0	P95	P7	A4	56
I/O	0	P96	P6	B4	59
I/O, V _{REF}	0	P97	P5	C4	62
I/O	0	-	P4	A3	65
I/O	0	P98	P3	B3	68
TCK	-	P99	P2	C3	-
V _{CCO}	0	P100	P1	A2	-
V _{CCO}	7	P100	P144	B2	-

04/18/01

Notes:

1. IRDY and TRDY can only be accessed when using Xilinx PCI cores.
2. See "VCCO Banks" for details on V_{CCO} banking.

Additional XC2S15 Package Pins

VQ100

Not Connected Pins					
P28	P29	-	-	-	-

11/02/00

TQ144

Not Connected Pins					
P42	P64	P78	P101	P104	P105
P116	P138	-	-	-	-

11/02/00

CS144

Not Connected Pins					
D3	D12	J4	K13	M3	M4
M10	N3	-	-	-	-

11/02/00

XC2S50 Device Pinouts

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
GND	-	P143	P1	GND*	-
TMS	-	P142	P2	D3	-
I/O	7	P141	P3	C2	149
I/O	7	-	-	A2	152
I/O	7	P140	P4	B1	155
I/O	7	-	-	E3	158
I/O	7	-	P5	D2	161
GND	-	-	-	GND*	-
I/O, V _{REF}	7	P139	P6	C1	164
I/O	7	-	P7	F3	167
I/O	7	-	-	E2	170
I/O	7	P138	P8	E4	173
I/O	7	P137	P9	D1	176
I/O	7	P136	P10	E1	179
GND	-	P135	P11	GND*	-
V _{CCO}	7	-	P12	V _{CCO} Bank 7*	-
V _{CCINT}	-	-	P13	V _{CCINT} *	-
I/O	7	P134	P14	F2	182
I/O	7	P133	P15	G3	185
I/O	7	-	-	F1	188
I/O	7	-	P16	F4	191
I/O	7	-	P17	F5	194
I/O	7	-	P18	G2	197
GND	-	-	P19	GND*	-
I/O, V _{REF}	7	P132	P20	H3	200
I/O	7	P131	P21	G4	203
I/O	7	-	-	H2	206
I/O	7	P130	P22	G5	209
I/O	7	-	P23	H4	212
I/O, IRDY ⁽¹⁾	7	P129	P24	G1	215
GND	-	P128	P25	GND*	-
V _{CCO}	7	P127	P26	V _{CCO} Bank 7*	-
V _{CCO}	6	P127	P26	V _{CCO} Bank 6*	-
I/O, TRDY ⁽¹⁾	6	P126	P27	J2	218
V _{CCINT}	-	P125	P28	V _{CCINT} *	-
I/O	6	P124	P29	H1	224
I/O	6	-	-	J4	227
I/O	6	P123	P30	J1	230
I/O, V _{REF}	6	P122	P31	J3	233

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
GND	-	-	P32	GND*	-
I/O	6	-	P33	K5	236
I/O	6	-	P34	K2	239
I/O	6	-	P35	K1	242
I/O	6	-	-	K3	245
I/O	6	P121	P36	L1	248
I/O	6	P120	P37	L2	251
V _{CCINT}	-	-	P38	V _{CCINT} *	-
V _{CCO}	6	-	P39	V _{CCO} Bank 6*	-
GND	-	P119	P40	GND*	-
I/O	6	P118	P41	K4	254
I/O	6	P117	P42	M1	257
I/O	6	P116	P43	L4	260
I/O	6	-	-	M2	263
I/O	6	-	P44	L3	266
I/O, V _{REF}	6	P115	P45	N1	269
GND	-	-	-	GND*	-
I/O	6	-	P46	P1	272
I/O	6	-	-	L5	275
I/O	6	P114	P47	N2	278
I/O	6	-	-	M4	281
I/O	6	P113	P48	R1	284
I/O	6	P112	P49	M3	287
M1	-	P111	P50	P2	290
GND	-	P110	P51	GND*	-
M0	-	P109	P52	N3	291
V _{CCO}	6	P108	P53	V _{CCO} Bank 6*	-
V _{CCO}	5	P107	P53	V _{CCO} Bank 5*	-
M2	-	P106	P54	R3	292
I/O	5	-	-	N5	299
I/O	5	P103	P57	T2	302
I/O	5	-	-	P5	305
I/O	5	-	P58	T3	308
GND	-	-	-	GND*	-
I/O, V _{REF}	5	P102	P59	T4	311
I/O	5	-	P60	M6	314
I/O	5	-	-	T5	317
I/O	5	P101	P61	N6	320
I/O	5	P100	P62	R5	323

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
I/O	5	P99	P63	P6	326
GND	-	P98	P64	GND*	-
V _{CCO}	5	-	P65	V _{CCO} Bank 5*	-
V _{CCINT}	-	P97	P66	V _{CCINT} *	-
I/O	5	P96	P67	R6	329
I/O	5	P95	P68	M7	332
I/O	5	-	P69	N7	338
I/O	5	-	P70	T6	341
I/O	5	-	P71	P7	344
GND	-	-	P72	GND*	-
I/O, V _{REF}	5	P94	P73	P8	347
I/O	5	-	P74	R7	350
I/O	5	-	-	T7	353
I/O	5	P93	P75	T8	356
V _{CCINT}	-	P92	P76	V _{CCINT} *	-
I, GCK1	5	P91	P77	R8	365
V _{CCO}	5	P90	P78	V _{CCO} Bank 5*	-
V _{CCO}	4	P90	P78	V _{CCO} Bank 4*	-
GND	-	P89	P79	GND*	-
I, GCK0	4	P88	P80	N8	366
I/O	4	P87	P81	N9	370
I/O	4	P86	P82	R9	373
I/O	4	-	-	N10	376
I/O	4	-	P83	T9	379
I/O, V _{REF}	4	P85	P84	P9	382
GND	-	-	P85	GND*	-
I/O	4	-	P86	M10	385
I/O	4	-	P87	R10	388
I/O	4	-	P88	P10	391
I/O	4	P84	P89	T10	397
I/O	4	P83	P90	R11	400
V _{CCINT}	-	P82	P91	V _{CCINT} *	-
V _{CCO}	4	-	P92	V _{CCO} Bank 4*	-
GND	-	P81	P93	GND*	-
I/O	4	P80	P94	M11	403
I/O	4	P79	P95	T11	406
I/O	4	P78	P96	N11	409
I/O	4	-	-	R12	412

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
I/O	4	-	P97	P11	415
I/O, V _{REF}	4	P77	P98	T12	418
GND	-	-	-	GND*	-
I/O	4	-	P99	T13	421
I/O	4	-	-	N12	424
I/O	4	P76	P100	R13	427
I/O	4	-	-	P12	430
I/O	4	P75	P101	P13	433
I/O	4	P74	P102	T14	436
GND	-	P73	P103	GND*	-
DONE	3	P72	P104	R14	439
V _{CCO}	4	P71	P105	V _{CCO} Bank 4*	-
V _{CCO}	3	P70	P105	V _{CCO} Bank 3*	-
PROGRAM	-	P69	P106	P15	442
I/O (INIT)	3	P68	P107	N15	443
I/O (D7)	3	P67	P108	N14	446
I/O	3	-	-	T15	449
I/O	3	P66	P109	M13	452
I/O	3	-	-	R16	455
I/O	3	-	P110	M14	458
GND	-	-	-	GND*	-
I/O, V _{REF}	3	P65	P111	L14	461
I/O	3	-	P112	M15	464
I/O	3	-	-	L12	467
I/O	3	P64	P113	P16	470
I/O	3	P63	P114	L13	473
I/O (D6)	3	P62	P115	N16	476
GND	-	P61	P116	GND*	-
V _{CCO}	3	-	P117	V _{CCO} Bank 3*	-
V _{CCINT}	-	-	P118	V _{CCINT} *	-
I/O (D5)	3	P60	P119	M16	479
I/O	3	P59	P120	K14	482
I/O	3	-	-	L16	485
I/O	3	-	P121	K13	488
I/O	3	-	P122	L15	491
I/O	3	-	P123	K12	494
GND	-	-	P124	GND*	-
I/O, V _{REF}	3	P58	P125	K16	497
I/O (D4)	3	P57	P126	J16	500

XC2S50 Device Pinouts (Continued)

XC2S50 Pad Name		TQ144	PQ208	FG256	Bndry Scan
Function	Bank				
I/O	0	-	-	D8	83
I/O	0	-	P188	A6	86
I/O, V _{REF}	0	P12	P189	B7	89
GND	-	-	P190	GND*	-
I/O	0	-	P191	C8	92
I/O	0	-	P192	D7	95
I/O	0	-	P193	E7	98
I/O	0	P11	P194	C7	104
I/O	0	P10	P195	B6	107
V _{CCINT}	-	P9	P196	V _{CCINT} *	-
V _{CCO}	0	-	P197	V _{CCO} Bank 0*	-
GND	-	P8	P198	GND*	-
I/O	0	P7	P199	A5	110
I/O	0	P6	P200	C6	113
I/O	0	-	P201	B5	116
I/O	0	-	-	D6	119
I/O	0	-	P202	A4	122
I/O, V _{REF}	0	P5	P203	B4	125
GND	-	-	-	GND*	-
I/O	0	-	P204	E6	128
I/O	0	-	-	D5	131
I/O	0	P4	P205	A3	134
I/O	0	-	-	C5	137
I/O	0	P3	P206	B3	140
TCK	-	P2	P207	C4	-
V _{CCO}	0	P1	P208	V _{CCO} Bank 0*	-
V _{CCO}	7	P144	P208	V _{CCO} Bank 7*	-

04/18/01

Notes:

1. IRDY and TRDY can only be accessed when using Xilinx PCI cores.
2. Pads labelled GND*, V_{CCINT}*, V_{CCO} Bank 0*, V_{CCO} Bank 1*, V_{CCO} Bank 2*, V_{CCO} Bank 3*, V_{CCO} Bank 4*, V_{CCO} Bank 5*, V_{CCO} Bank 6*, V_{CCO} Bank 7* are internally bonded to independent ground or power planes within the package.
3. See "VCCO Banks" for details on V_{CCO} banking.

Additional XC2S50 Package Pins

TQ144

Not Connected Pins					
P104	P105	-	-	-	-

11/02/00

Additional XC2S100 Package Pins

TQ144

Not Connected Pins					
P104	P105	-	-	-	-

11/02/00

PQ208

Not Connected Pins					
P55	P56	-	-	-	-

11/02/00

FG256

V _{CCINT} Pins					
C3	C14	D4	D13	E5	E12
M5	M12	N4	N13	P3	P14
V _{CCO} Bank 0 Pins					
E8	F8	-	-	-	-
V _{CCO} Bank 1 Pins					
E9	F9	-	-	-	-
V _{CCO} Bank 2 Pins					
H11	H12	-	-	-	-
V _{CCO} Bank 3 Pins					
J11	J12	-	-	-	-
V _{CCO} Bank 4 Pins					
L9	M9	-	-	-	-
V _{CCO} Bank 5 Pins					
L8	M8	-	-	-	-
V _{CCO} Bank 6 Pins					
J5	J6	-	-	-	-
V _{CCO} Bank 7 Pins					
H5	H6	-	-	-	-
GND Pins					
A1	A16	B2	B15	F6	F7
F10	F11	G6	G7	G8	G9
G10	G11	H7	H8	H9	H10
J7	J8	J9	J10	K6	K7
K8	K9	K10	K11	L6	L7
L10	L11	R2	R15	T1	T16
Not Connected Pins					
P4	R4	-	-	-	-

11/02/00

FG456

V _{CCINT} Pins					
E5	E18	F6	F17	G7	G8
G9	G14	G15	G16	H7	H16
J7	J16	P7	P16	R7	R16
T7	T8	T9	T14	T15	T16
U6	U17	V5	V18	-	-
V _{CCO} Bank 0 Pins					

Additional XC2S100 Package Pins (Continued)

F10	F7	F8	F9	G10	G11
V _{CCO} Bank 1 Pins					
F13	F14	F15	F16	G12	G13
V _{CCO} Bank 2 Pins					
G17	H17	J17	K16	K17	L16
V _{CCO} Bank 3 Pins					
M16	N16	N17	P17	R17	T17
V _{CCO} Bank 4 Pins					
T12	T13	U13	U14	U15	U16
V _{CCO} Bank 5 Pins					
T10	T11	U10	U7	U8	U9
V _{CCO} Bank 6 Pins					
M7	N6	N7	P6	R6	T6
V _{CCO} Bank 7 Pins					
G6	H6	J6	K6	K7	L7
GND Pins					
A1	A22	B2	B21	C3	C20
J9	J10	J11	J12	J13	J14
K9	K10	K11	K12	K13	K14
L9	L10	L11	L12	L13	L14
M9	M10	M11	M12	M13	M14
N9	N10	N11	N12	N13	N14
P9	P10	P11	P12	P13	P14
Y3	Y20	AA2	AA21	AB1	AB22
Not Connected Pins					
A2	A4	A5	A6	A12	A13
A14	A15	A17	B3	B6	B8
B11	B14	B16	B19	C1	C2
C8	C9	C12	C18	C22	D1
D4	D5	D10	D18	D19	D21
E4	E11	E13	E15	E16	E17
E19	E22	F4	F11	F22	G2
G3	G4	G19	G22	H1	H21
J1	J3	J4	J19	J20	K2
K18	K19	L2	L5	L18	L19
M2	M6	M17	M18	M21	N1
N5	N19	P1	P5	P19	P22
R1	R3	R20	R22	T5	T19
U3	U11	U18	V1	V2	V10
V12	V17	V3	V4	V6	V8
V20	V21	V22	W4	W5	W9
W13	W14	W15	W16	W19	Y5
Y14	Y18	Y22	AA1	AA3	AA6
AA9	AA10	AA11	AA16	AA17	AA18
AA22	AB3	AB4	AB7	AB8	AB12
AB14	AB21	-	-	-	-

11/02/00

Additional XC2S150 Package Pins

PQ208

Not Connected Pins					
P55	P56	-	-	-	-

11/02/00

FG256

V _{CCINT} Pins					
C3	C14	D4	D13	E5	E12
M5	M12	N4	N13	P3	P14
V _{CCO} Bank 0 Pins					
E8	F8	-	-	-	-
V _{CCO} Bank 1 Pins					
E9	F9	-	-	-	-
V _{CCO} Bank 2 Pins					
H11	H12	-	-	-	-
V _{CCO} Bank 3 Pins					
J11	J12	-	-	-	-
V _{CCO} Bank 4 Pins					
L9	M9	-	-	-	-
V _{CCO} Bank 5 Pins					
L8	M8	-	-	-	-
V _{CCO} Bank 6 Pins					
J5	J6	-	-	-	-
V _{CCO} Bank 7 Pins					
H5	H6	-	-	-	-
GND Pins					
A1	A16	B2	B15	F6	F7
F10	F11	G6	G7	G8	G9
G10	G11	H7	H8	H9	H10
J7	J8	J9	J10	K6	K7
K8	K9	K10	K11	L6	L7
L10	L11	R2	R15	T1	T16
Not Connected Pins					
P4	R4	-	-	-	-

11/02/00

Additional XC2S150 Package Pins (Continued)

FG456

V _{CCINT} Pins					
E5	E18	F6	F17	G7	G8
G9	G14	G15	G16	H7	H16
J7	J16	P7	P16	R7	R16
T7	T8	T9	T14	T15	T16
U6	U17	V5	V18	-	-
V _{CCO} Bank 0 Pins					
F7	F8	F9	F10	G10	G11
V _{CCO} Bank 1 Pins					
F13	F14	F15	F16	G12	G13
V _{CCO} Bank 2 Pins					
G17	H17	J17	K16	K17	L16
V _{CCO} Bank 3 Pins					
M16	N16	N17	P17	R17	T17
V _{CCO} Bank 4 Pins					
T12	T13	U13	U14	U15	U16
V _{CCO} Bank 5 Pins					
T10	T11	U7	U8	U9	U10
V _{CCO} Bank 6 Pins					
M7	N6	N7	P6	R6	T6
V _{CCO} Bank 7 Pins					
G6	H6	J6	K6	K7	L7
GND Pins					
A1	A22	B2	B21	C3	C20
J9	J10	J11	J12	J13	J14
K9	K10	K11	K12	K13	K14
L9	L10	L11	L12	L13	L14
M9	M10	M11	M12	M13	M14
N9	N10	N11	N12	N13	N14
P9	P10	P11	P12	P13	P14
Y3	Y20	AA2	AA21	AB1	AB22
Not Connected Pins					
A2	A6	A12	A13	A14	B11
B16	C2	C8	C9	D1	D4
D18	D19	E13	E17	E19	F11
G2	G22	H21	J1	J4	K2
K18	K19	L2	L19	M2	M17
M21	N1	P1	P5	P22	R3
R20	R22	U3	U18	V6	W4
W13	W15	W19	Y5	Y22	AA1
AA3	AA9	AA10	AA11	AA16	AB7
AB8	AB12	AB14	AB21	-	-

11/02/00

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
I/O	6	-	-	T2	449
I/O	6	P43	L4	U1	452
GND	-	-	GND*	GND*	-
I/O	6	-	M2	R5	455
I/O	6	-	-	V1	458
I/O	6	-	-	T5	461
I/O	6	P44	L3	U2	464
I/O, V _{REF}	6	P45	N1	T3	467
V _{CCO}	6	-	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	-	GND*	GND*	-
I/O	6	P46	P1	T4	470
I/O	6	-	L5	W1	473
GND	-	-	GND*	GND*	-
I/O	6	-	-	V2	476
I/O	6	-	-	U4	482
I/O, V _{REF}	6	P47	N2	Y1	485
GND	-	-	GND*	GND*	-
I/O	6	-	M4	W2	488
I/O	6	-	-	V3	491
I/O	6	-	-	V4	494
I/O	6	P48	R1	Y2	500
I/O	6	P49	M3	W3	503
M1	-	P50	P2	U5	506
GND	-	P51	GND*	GND*	-
M0	-	P52	N3	AB2	507
V _{CCO}	6	P53	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
V _{CCO}	5	P53	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
M2	-	P54	R3	Y4	508
I/O	5	-	-	W5	518
I/O	5	-	-	AB3	521
I/O	5	-	N5	V7	524
GND	-	-	GND*	GND*	-
I/O, V _{REF}	5	P57	T2	Y6	527
I/O	5	-	-	AA4	530
I/O	5	-	-	AB4	536
I/O	5	-	P5	W6	539
I/O	5	P58	T3	Y7	542
GND	-	-	GND*	GND*	-

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name		PQ208	FG256	FG456	Bndry Scan
Function	Bank				
V _{CCO}	5	-	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
I/O, V _{REF}	5	P59	T4	AA5	545
I/O	5	P60	M6	AB5	548
I/O	5	-	-	V8	551
I/O	5	-	-	AA6	554
I/O	5	-	T5	AB6	557
GND	-	-	GND*	GND*	-
I/O	5	P61	N6	AA7	560
I/O	5	-	-	W7	563
I/O, V _{REF}	5	P62	R5	W8	569
I/O	5	P63	P6	Y8	572
GND	-	P64	GND*	GND*	-
V _{CCO}	5	P65	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
V _{CCINT}	-	P66	V _{CCINT} *	V _{CCINT} *	-
I/O	5	P67	R6	AA8	575
I/O	5	P68	M7	V9	578
I/O	5	-	-	AB8	581
I/O	5	-	-	W9	584
I/O	5	-	-	AB9	587
GND	-	-	GND*	GND*	-
I/O	5	P69	N7	Y9	590
I/O	5	-	-	V10	593
I/O	5	-	-	AA9	596
I/O	5	P70	T6	W10	599
I/O	5	P71	P7	AB10	602
GND	-	P72	GND*	GND*	-
V _{CCO}	5	-	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
I/O, V _{REF}	5	P73	P8	Y10	605
I/O	5	P74	R7	V11	608
I/O	5	-	-	AA10	614
I/O	5	-	T7	W11	617
I/O	5	P75	T8	AB11	620
I/O	5	-	-	U11	623
V _{CCINT}	-	P76	V _{CCINT} *	V _{CCINT} *	-
I, GCK1	5	P77	R8	Y11	635
V _{CCO}	5	P78	V _{CCO} Bank 5*	V _{CCO} Bank 5*	-
V _{CCO}	4	P78	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	P79	GND*	GND*	-

Additional XC2S200 Package Pins (Continued)

11/02/00

FG456

V _{CCINT} Pins					
E5	E18	F6	F17	G7	G8
G9	G14	G15	G16	H7	H16
J7	J16	P7	P16	R7	R16
T7	T8	T9	T14	T15	T16
U6	U17	V5	V18	-	-
V _{CCO} Bank 0 Pins					
F7	F8	F9	F10	G10	G11
V _{CCO} Bank 1 Pins					
F13	F14	F15	F16	G12	G13
V _{CCO} Bank 2 Pins					
G17	H17	J17	K16	K17	L16
V _{CCO} Bank 3 Pins					
M16	N16	N17	P17	R17	T17
V _{CCO} Bank 4 Pins					
T12	T13	U13	U14	U15	U16
V _{CCO} Bank 5 Pins					
T10	T11	U7	U8	U9	U10
V _{CCO} Bank 6 Pins					
M7	N6	N7	P6	R6	T6
V _{CCO} Bank 7 Pins					

Additional XC2S200 Package Pins (Continued)

G6	H6	J6	K6	K7	L7
GND Pins					
A1	A22	B2	B21	C3	C20
J9	J10	J11	J12	J13	J14
K9	K10	K11	K12	K13	K14
L9	L10	L11	L12	L13	L14
M9	M10	M11	M12	M13	M14
N9	N10	N11	N12	N13	N14
P9	P10	P11	P12	P13	P14
Y3	Y20	AA2	AA21	AB1	AB22
Not Connected Pins					
A2	A6	A12	B11	B16	C2
D1	D4	D18	D19	E17	E19
G2	G22	L2	L19	M2	M21
R3	R20	U3	U18	V6	W4
W19	Y5	Y22	AA1	AA3	AA11
AA16	AB7	AB12	AB21	-	-

11/02/00

Revision History

Version No.	Date	Description
2.0	09/18/00	Sectioned the Spartan-II Family data sheet into four modules. Corrected all known errors in the pinout tables.
2.1	10/04/00	Added notes requiring $\overline{\text{PWDN}}$ to be tied to V _{CCINT} when unused.
2.2	11/02/00	Removed the Power Down feature.
2.3	03/05/01	Added notes on pinout tables for IRDY and TRDY.
2.4	04/30/01	Reinstated XC2S50 V _{CCO} Bank 7, GND, and "not connected" pins missing in version 2.3.
2.5	09/03/03	Added caution about Not Connected Pins to XC2S30 pinout tables on page 76 .
2.8	06/13/08	Added " Package Overview " section. Added notes to clarify shared V _{CCO} banks. Updated description and links. Updated all modules for continuous page, figure, and table numbering. Synchronized all modules to v2.8.